

Q3

--SUMMARY OF THE INVENTION--

Page 3, after line 2 and before line 3, insert:

Q4

--BRIEF DESCRIPTION OF THE DRAWINGS--

Page 3, line 16, insert:

Q5

--DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS--

IN THE CLAIMS

Please amend claims 1 and 2 as follows:

Q6

1. (Amended) An electro-optical device having an ITO (indium tin oxide) layer and a SiN layer near the ITO layer, wherein said ITO layer is deposited prior to the SiN layer and an intermediate layer of silicon oxide is provided between the ITO layer and the SiN layer.

2. (Amended) The electro-optical device of claim 1, wherein the electro-optical device is a fingerprint sensor.

Please add claims 4 to 6 as follows:

Q7

4. (Newly added) A method for improving the optical and electrical properties of an ITO layer and thereby the quality of an electro-optical device, comprising the steps of:

depositing an ITO layer; and

providing an intermediate layer of silicon oxide between said ITO layer and an SiN layer provided by means of chemical vapor deposition.